

## Features

- Low Forward Voltage Drop
- Fast Switching
- Ultra-Small Leadless Surface Mount Package
- PN Junction Guard Ring for Transient and ESD Protection
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

## Mechanical Data

- Case: X1-DFN1006-2
- Case Material: Molded Plastic, "Green" Molding Compound.  
UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: Cathode Bar/Dot
- Terminals: Finish - NiPdAu Annealed over Copper Leadframe.  
Solderable per MIL-STD-202, Method 208 <sup>(e4)</sup>
- Weight: 0.001 grams (Approximate)

X1-DFN1006-2



Top View



Bottom View

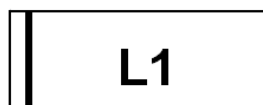
## Ordering Information (Note 4)

| Part Number | Case         | Packaging          |
|-------------|--------------|--------------------|
| BAT54LP-7   | X1-DFN1006-2 | 3,000/Tape & Reel  |
| BAT54LP-7B  | X1-DFN1006-2 | 10,000/Tape & Reel |

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
  2. See [http://www.diodes.com/quality/lead\\_free.html](http://www.diodes.com/quality/lead_free.html) for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

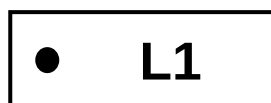
## Marking Information

BAT54LP-7



Top View  
Bar Denotes Cathode Side

Or

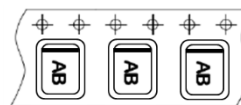


Top View  
Dot Denotes Cathode Side

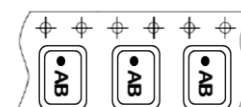
BAT54LP-7B



Top View  
Bar Denotes Cathode Side



Bar Denotes Cathode side



Dot Denotes Cathode side

L1 = Product Type Marking Code

**Maximum Ratings** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

| Characteristic                            | Symbol    | Value | Unit |
|-------------------------------------------|-----------|-------|------|
| Peak Repetitive Reverse Voltage           | $V_{RRM}$ | 30    | V    |
| Working Peak Reverse Voltage              | $V_{RWM}$ |       |      |
| DC Blocking Voltage                       | $V_R$     |       |      |
| Forward Continuous Current                | $I_F$     | 200   | mA   |
| Repetitive Peak Forward Current           | $I_{FRM}$ | 300   | mA   |
| Forward Surge Current @ $t < 1.0\text{s}$ | $I_{FSM}$ | 600   | mA   |

**Thermal Characteristics**

| Characteristic                                       | Symbol          | Value       | Unit               |
|------------------------------------------------------|-----------------|-------------|--------------------|
| Power Dissipation (Note 5)                           | $P_D$           | 250         | mW                 |
| Thermal Resistance, Junction to Ambient Air (Note 5) | $R_{\theta JA}$ | 400         | $^\circ\text{C/W}$ |
| Operating and Storage Temperature Range              | $T_J, T_{STG}$  | -65 to +125 | $^\circ\text{C}$   |

**Electrical Characteristics** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

| Characteristic                     | Symbol      | Min | Typ | Max                               | Unit          | Test Condition                                                                                                   |
|------------------------------------|-------------|-----|-----|-----------------------------------|---------------|------------------------------------------------------------------------------------------------------------------|
| Reverse Breakdown Voltage (Note 6) | $V_{(BR)R}$ | 30  | —   | —                                 | V             | $I_R = 100\mu\text{A}$                                                                                           |
| Forward Voltage                    | $V_F$       | —   | —   | 240<br>320<br>400<br>500<br>1,000 | mV            | $I_F = 0.1\text{mA}$<br>$I_F = 1\text{mA}$<br>$I_F = 10\text{mA}$<br>$I_F = 30\text{mA}$<br>$I_F = 100\text{mA}$ |
| Reverse Leakage Current (Note 6)   | $I_R$       | —   | —   | 2.0                               | $\mu\text{A}$ | $V_R = 25\text{V}$                                                                                               |
| Total Capacitance                  | $C_T$       | —   | —   | 10                                | pF            | $V_R = 1.0\text{V}$ , $f = 1.0\text{MHz}$                                                                        |
| Reverse Recovery Time              | $t_{RR}$    | —   | —   | 5.0                               | ns            | $I_F = 10\text{mA}$ through $I_R = 10\text{mA}$<br>to $I_R = 1.0\text{mA}$ , $R_L = 100\Omega$                   |

Notes: 5. Part mounted on FR-4 PC board with recommended pad layout, which can be found on our website at <http://www.diodes.com>.  
 6. Short duration pulse test used to minimize self-heating effect.

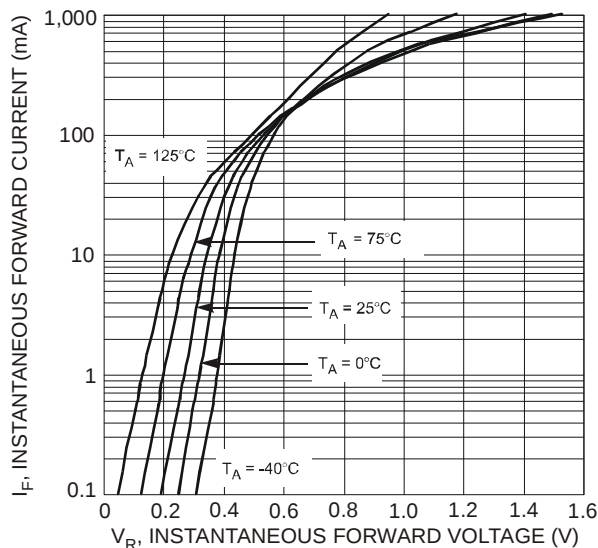


Fig. 1 Typical Forward Characteristics

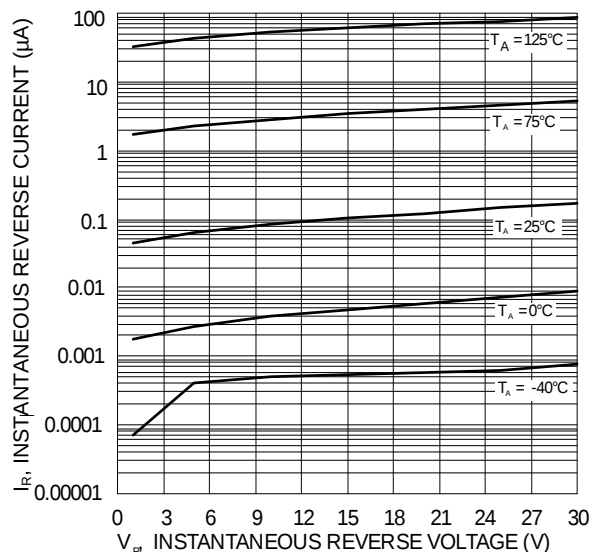
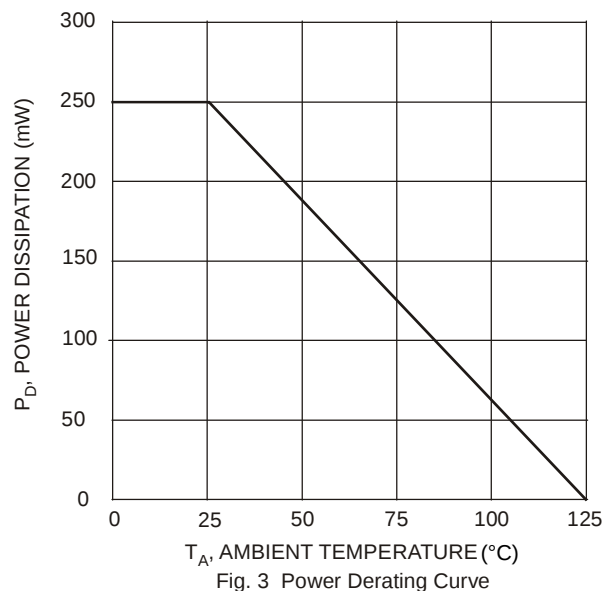


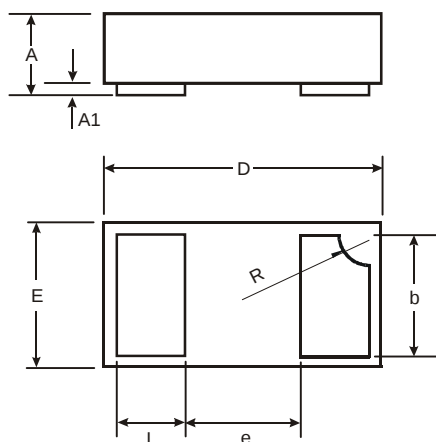
Fig. 2 Typical Reverse Characteristics



## Package Outline Dimensions

Please see AP02001 at [http://www.diodes.com/\\_files/datasheets/ap02001.pdf](http://www.diodes.com/_files/datasheets/ap02001.pdf) for the latest version.

### X1-DFN1006-2

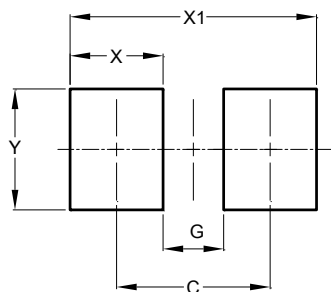


| X1-DFN1006-2         |      |       |      |
|----------------------|------|-------|------|
| Dim                  | Min  | Max   | Typ  |
| A                    | 0.47 | 0.53  | 0.50 |
| A1                   | 0    | 0.05  | 0.03 |
| b                    | 0.45 | 0.55  | 0.50 |
| D                    | 0.95 | 1.075 | 1.00 |
| E                    | 0.55 | 0.675 | 0.60 |
| e                    | -    | -     | 0.40 |
| L                    | 0.20 | 0.30  | 0.25 |
| R                    | 0.05 | 0.15  | 0.10 |
| All Dimensions in mm |      |       |      |

## Suggested Pad Layout

Please see AP02001 at [http://www.diodes.com/\\_files/datasheets/ap02001.pdf](http://www.diodes.com/_files/datasheets/ap02001.pdf) for the latest version.

### X1-DFN1006-2



| Dimensions | Value (in mm) |
|------------|---------------|
| C          | 0.70          |
| G          | 0.30          |
| X          | 0.40          |
| X1         | 1.10          |
| Y          | 0.70          |

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